National Semiconductor

August 1995

74F350
4-Bit Shifter with TRI-STATE® Outputs

General Description

The 'F350 is a specialized multiplexer that accepts a 4-bit word and shifts it 0, 1, 2 or 3 places, as determined by two Select (S_0, S_1) inputs. For expansion to longer words, three linking inputs are provided for lower-order bits; thus two packages can shift an 8-bit word, four packages a 16-bit word, etc. Shifting by more than three places is accomplished by paralleling the TRI-STATE outputs of different packages and using the Output Enable ($\overline{OE}$) inputs as a third Select level. With appropriate interconnections, the 'F350 can perform zero-backfill, sign-extend or end-around (barrel) shift functions.

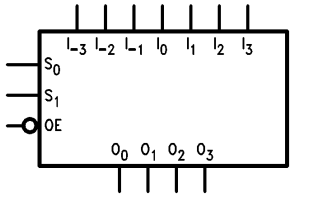
Features

- Linking inputs for word expansion
- TRI-STATE outputs for extending shift range

Commercial	Package Number	Package Description
74F350PC	N16E	16-Lead (0.300″ Wide) Molded Dual-In-Line
74F350SC (Note 1)	M16A	16-Lead (0.150″ Wide) Molded Small Outline, JEDEC
74F350SJ (Note 1)	M16D	16-Lead (0.300″ Wide) Molded Small Outline, EIAJ

Note 1: Devices also available in 13″ reel. Use suffix = SCX and SJX.

Logic Symbols



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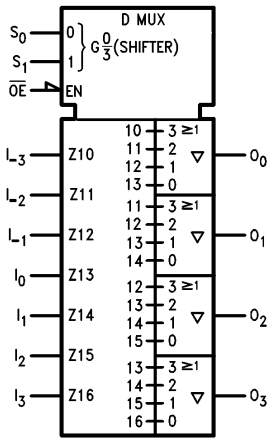
IEEE/IEC



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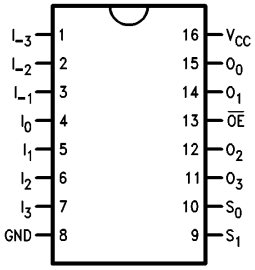
Connection Diagram

Pin Assignment for DIP and SOIC



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RRD-B30M105/Printed in U. S. A.

Unit Loading/Fan Out

Pin Names	Description	74F	
		U.L. HIGH/LOW	Input I_{IH}/I_{IL} Output I_{OH}/I_{OL}
S_0, S_1	Select Inputs	1.0/2.0	20 μA/ $-$1.2 mA
I_{-3}–I_3	Data Inputs	1.0/2.0	20 μA/ $-$1.2 mA
$\overline{OE}$	Output Enable Input (Active LOW)	1.0/2.0	20 μA/ $-$1.2 mA
O_0–O_3	TRI-STATE Outputs	150/40 (33.3)	$-$3 mA/24 mA (20 mA)

Functional Description

The 'F350 is operationally equivalent to a 4-input multiplexer with the inputs connected so that the select code causes successive one-bit shifts of the data word. This internal connection makes it possible to perform shifts of 0, 1, 2 or 3 places on words of any length.

A 4-bit data word is introduced at the I_n inputs and is shifted according to the code applied to the select inputs S_0, S_1. Outputs O_0–O_3 are TRI-STATE, controlled by an active LOW output enable ($\overline{OE}$). When $\overline{OE}$ is LOW, data outputs will follow selected data inputs; when HIGH, the data outputs will be forced to the high impedance state. This feature allows shifters to be cascaded on the same output lines or to a common bus. The shift function can be logical, with zeros pulled in at either or both ends of the shifting field; arithmetic, where the sign bit is repeated during a shift down; or end around, where the data word forms a continuous loop.

Logic Equations

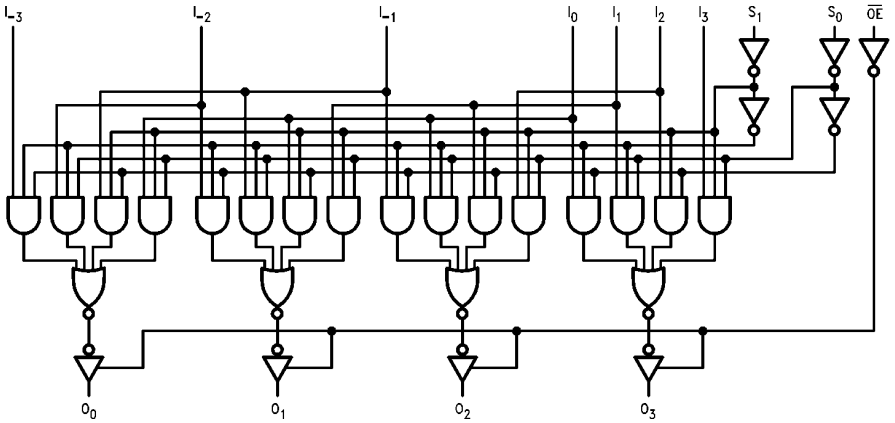
$$O_0 = \overline{S}_0\overline{S}_1I_0 + S_0\overline{S}_1I_{-1} + \overline{S}_0S_1I_{-2} + S_0S_1I_{-3}$$
$$O_1 = \overline{S}_0\overline{S}_1I_1 + S_0\overline{S}_1I_0 + \overline{S}_0S_1I_{-1} + S_0S_1I_{-2}$$
$$O_2 = \overline{S}_0\overline{S}_1I_2 + S_0\overline{S}_1I_1 + \overline{S}_0S_1I_0 + S_0S_1I_{-1}$$
$$O_3 = \overline{S}_0\overline{S}_1I_3 + S_0\overline{S}_1I_2 + \overline{S}_0S_1I_1 + S_0S_1I_0$$

Truth Table

Inputs			Outputs			
$\overline{OE}$	S_1	S_0	O_0	O_1	O_2	O_3
H	X	X	Z	Z	Z	Z
L	L	L	I_0	I_1	I_2	I_3
L	L	H	I_{-1}	I_0	I_1	I_2
L	H	L	I_{-2}	I_{-1}	I_0	I_1
L	H	H	I_{-3}	I_{-2}	I_{-1}	I_0

H = HIGH Voltage Level
L = LOW Voltage Level
X = Immaterial
Z = High Impedance

Logic Diagram



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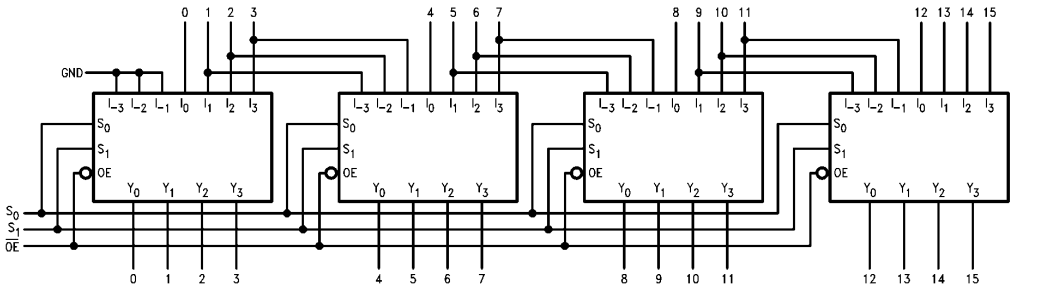
Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Applications

16-Bit Shift-Up 0 to 3 Places, Zero Backfill



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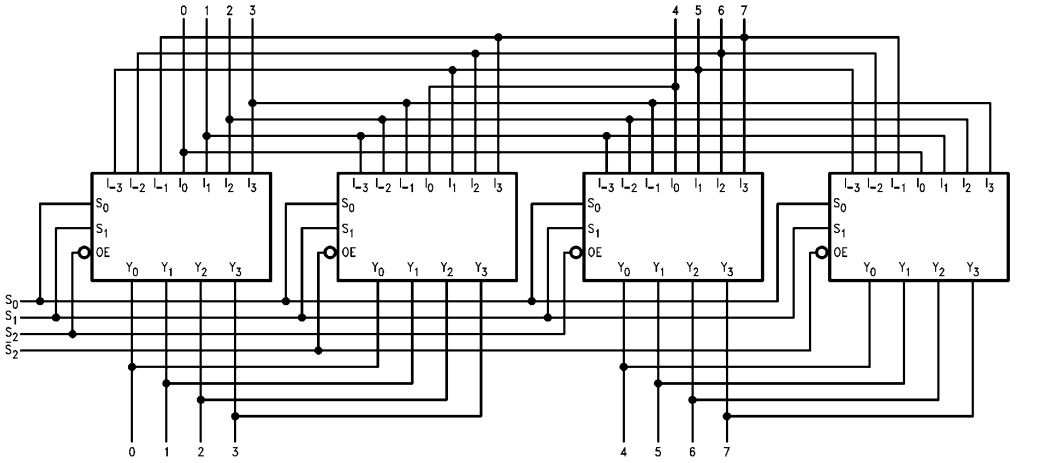
Function Table

S_1	S_0	Shift Function
L	L	No Shift
L	H	Shift 1 Place
H	L	Shift 2 Places
H	H	Shift 3 Places

8-Bit End Around Shift 0 to 7 Places



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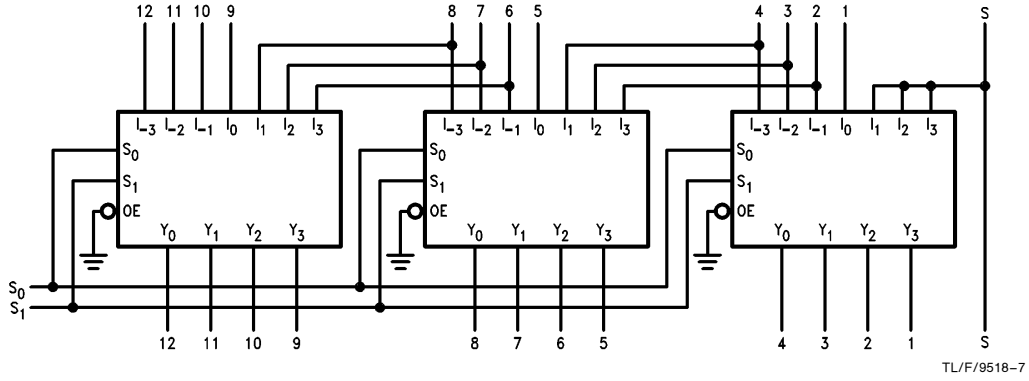
Applications (Continued)

Function Table

S_2	S_1	S_0	Shift Function
L	L	L	No Shift
L	L	H	Shift End Around 1
L	H	L	Shift End Around 2
L	H	H	Shift End Around 3
H	L	L	Shift End Around 4
H	L	H	Shift End Around 5
H	H	L	Shift End Around 6
H	H	H	Shift End Around 7

13-Bit Twos Complement Scaler



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Function Table

S_1	S_0	Scale
L	L ÷ 8	⅛
L	H ÷ 4	¼
H	L ÷ 2	½
H	H No Change	1

Absolute Maximum Ratings (Note 1)

Storage Temperature	−65°C to +150°C
Ambient Temperature under Bias	−55°C to +125°C
Junction Temperature under Bias	−55°C to +175°C
Plastic	−55°C to +150°C
V_{CC} Pin Potential to Ground Pin	−0.5V to +7.0V
Input Voltage (Note 2)	−0.5V to +7.0V
Input Current (Note 2)	−30 mA to +5.0 mA
Voltage Applied to Output in HIGH State (with V_{CC} = 0V)	
Standard Output	−0.5V to V_{CC}
TRI-STATE Output	−0.5V to +5.5V
Current Applied to Output in LOW State (Max)	twice the rated I_{OL} (mA)

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

Recommended Operating Conditions

Free Air Ambient Temperature	
Commercial	0°C to +70°C
Supply Voltage	
Commercial	+4.5V to +5.5V

DC Electrical Characteristics

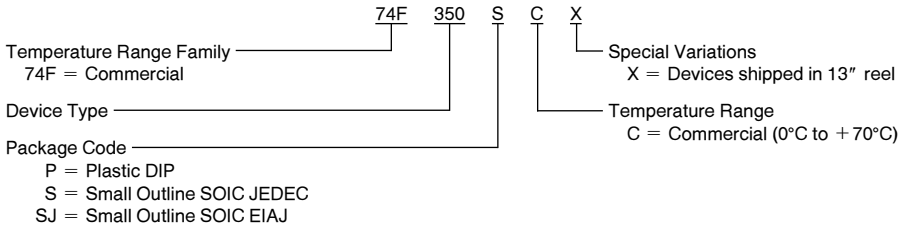
Symbol	Parameter		74F			Units	V_{CC}	Conditions
			Min	Typ	Max			
V_{IH}	Input HIGH Voltage		2.0			V		Recognized as a HIGH Signal
V_{IL}	Input LOW Voltage				0.8	V		Recognized as a LOW Signal
V_{CD}	Input Clamp Diode Voltage				−1.2	V	Min	I_{IN} = −18 mA
V_{OH}	Output HIGH Voltage	74F 10% V_{CC}	2.5			V	Min	I_{OH} = −1 mA
		74F 10% V_{CC}	2.4					I_{OH} = −3 mA
		74F 5% V_{CC}	2.7					I_{OH} = −1 mA
		74F 10% V_{CC}	2.7					I_{OH} = −3 mA
V_{OL}	Output LOW Voltage	74F 10% V_{CC}			0.5	V	Min	I_{OL} = 24 mA
I_{IH}	Input HIGH Current	74F			5.0	μA	Max	V_{IN} = 2.7V
I_{BVI}	Input HIGH Current Breakdown Test	74F			7.0	μA	Max	V_{IN} = 7.0V
I_{CEX}	Output HIGH Leakage Current	74F			50	μA	Max	V_{OUT} = V_{CC}
V_{ID}	Input Leakage Test	74F	4.75			V	0.0	I_{ID} = 1.9 μA All Other Pins Grounded
I_{OD}	Output Leakage Circuit Current	74F			3.75	μA	0.0	V_{IOD} = 150 mV All Other Pins Grounded
I_{IL}	Input LOW Current				−1.2	mA	Max	V_{IN} = 0.5V
I_{OZH}	Output Leakage Current				50	μA	Max	V_{OUT} = 2.7V
I_{OZL}	Output Leakage Current				−50	μA	Max	V_{OUT} = 0.5V
I_{OS}	Output Short-Circuit Current		−60		−150	mA	Max	V_{OUT} = 0V
I_{ZZ}	Bus Drainage Test				500	μA	0.0V	V_{OUT} = 5.25V
I_{CCH}	Power Supply Current			34	42	mA	Max	V_O = HIGH
I_{CCL}	Power Supply Current			40	57	mA	Max	V_O = LOW
I_{CCZ}	Power Supply Current			40	57	mA	Max	V_O = HIGH Z

AC Electrical Characteristics

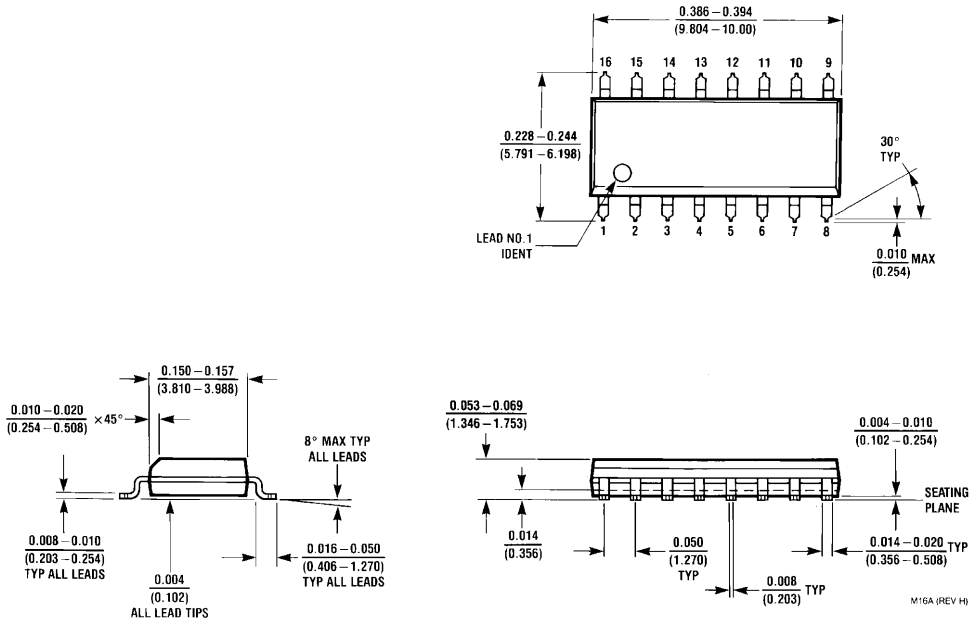
Symbol	Parameter	74F $T_A = +25°C$, $V_{CC} = +5.0V$, $C_L = 50$ pF			74F T_A, V_{CC} = Com, $C_L = 50$ pF		Units
		Min	Typ	Max	Min	Max	
t_{PLH}	Propagation Delay	3.0	4.5	6.0	3.0	7.0	ns
t_{PHL}	I_n to O_n	2.5	4.0	5.5	2.5	6.5	
t_{PLH}	Propagation Delay	4.0	7.8	10.0	4.0	13.5	ns
t_{PHL}	S_n to O_n	3.0	6.5	8.5	3.0	9.5	
t_{PZH}	Output Enable Time	2.5	5.0	7.0	2.5	8.0	ns
t_{PZL}		4.0	7.0	9.0	4.0	10.0	
t_{PHZ}	Output Disable Time	2.0	3.9	5.5	2.0	6.5	
t_{PLZ}		2.0	4.0	5.5	2.0	7.5	

Ordering Information

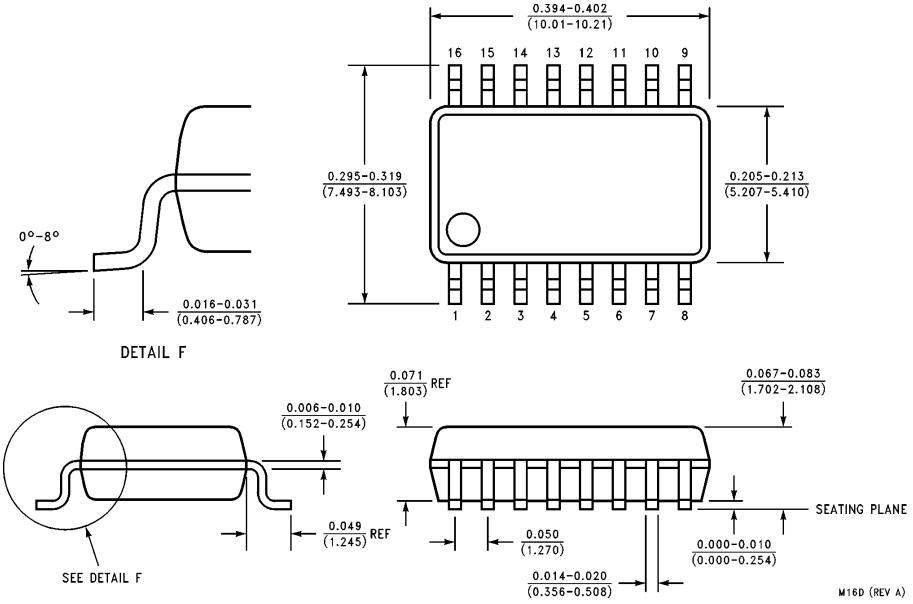
The device number is used to form part of a simplified purchasing code where the package type and temperature range are defined as follows:



Physical Dimensions inches (millimeters)

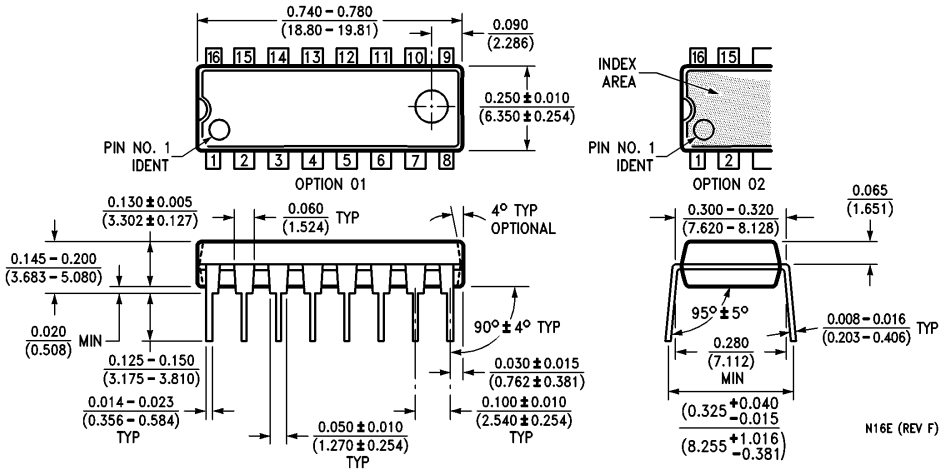


16-Lead (0.150″ Wide) Molded Small Outline Package, JEDEC (S)
NS Package Number M16A



16-Lead (0.300″ Wide) Molded Small Outline Package, EIAJ (SJ)
NS Package Number M16D

Physical Dimensions inches (millimeters) (Continued)



16-Lead (0.300″ Wide) Molded Dual-In-Line Package (P)
NS Package Number N16E

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